



SOT-23 Plastic-Encapsulate Transistors

BC856A, B TRANSISTOR (PNP)

BC857A, B,C

BC858A, B,C

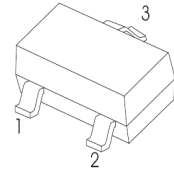
FEATURES

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage		
	BC856	-80	V
	BC857	-50	
BC858	-30		
V _{CEO}	Collector-Emitter Voltage		
	BC856	-65	V
	BC857	-45	
BC858	-30		
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current –Continuous	-0.1	A
P _C	Collector Power Dissipation	200	mW
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-65-150	°C

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

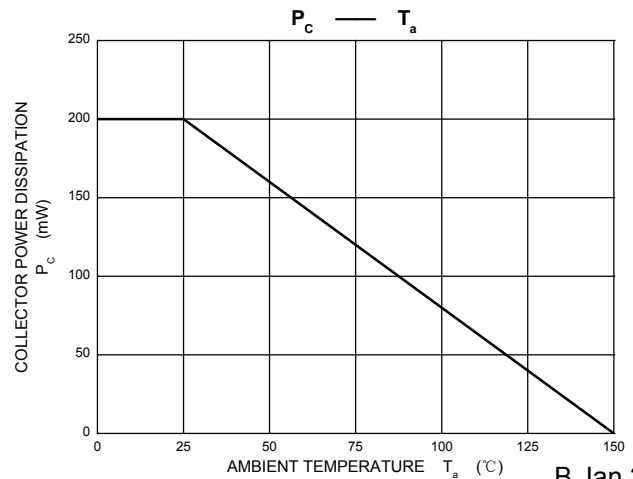
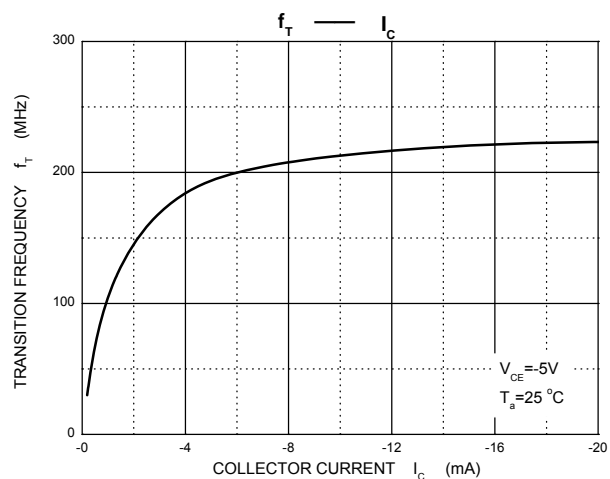
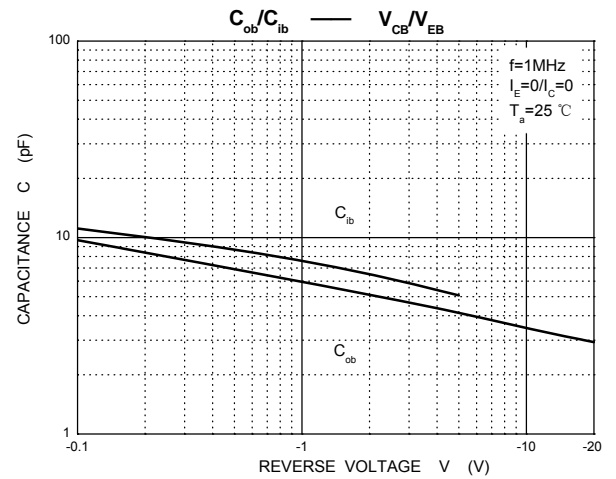
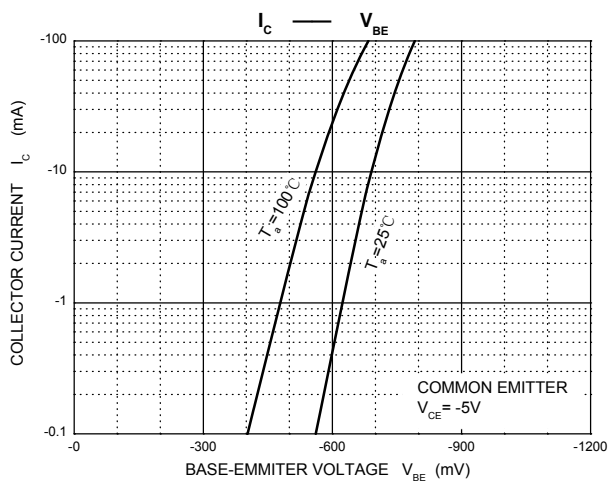
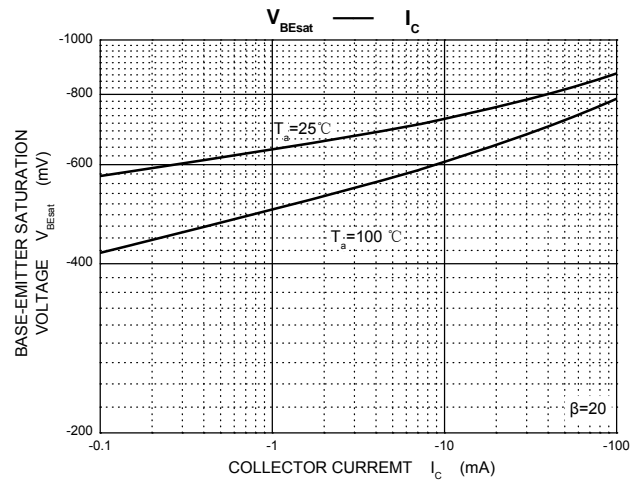
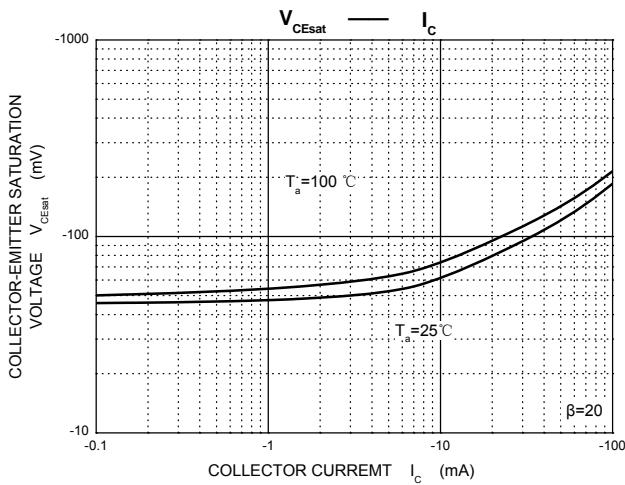
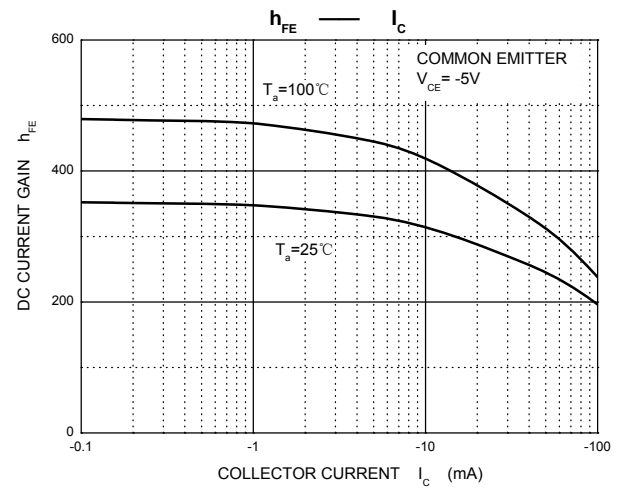
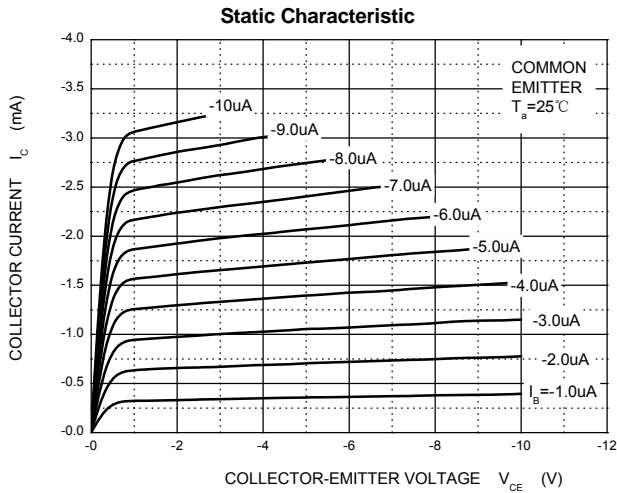
DEVICE MARKING

BC856A=3A; BC856B=3B;
BC857A=3E;BC857B=3F;BC857C=3G;
BC858A=3J; BC858B=3K; BC858C=3L

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage BC856 BC857 BC858	V _{CBO}	I _C = -10μA, I _E =0	-80 -50 -30		V
Collector-emitter breakdown voltage BC856 BC857 BC858	V _{CEO}	I _C = -10mA, I _B =0	-65 -45 -30		V
Emitter-base breakdown voltage	V _{EBO}	I _E = -1μA, I _C =0	-5		V
Collector cut-off current BC856 BC857 BC858	I _{CBO}	V _{CB} = -70 V, I _E =0 V _{CB} = -45 V, I _E =0 V _{CB} = -25 V, I _E =0		-0.1	μA
Collector cut-off current BC856 BC857 BC858	I _{CEO}	V _{CE} = -60 V, I _B =0 V _{CE} = -40 V, I _B =0 V _{CE} = -25 V, I _B =0		-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -5 V, I _C =0		-0.1	μA
DC current gain BC856A, 857A,858A BC856B, 857B,858B BC857C,BC858C	h _{FE}	V _{CE} = -5V,I _C = -2mA	125 220 420	250 475 800	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-100mA,I _B = -5 mA		-0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = -100mA, I _B = -5mA		-1.1	V
Transition frequency	f _T	V _{CE} = -5 V, I _C = -10mA f=100MHz	100		MHz
Collector capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		4.5	pF

Typical Characteristics BC856/BC857/BC858



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